

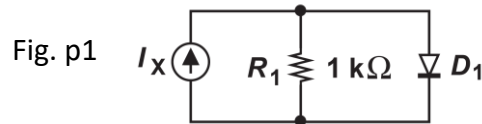
## The final exam of " Introduction to Electronics" on 29.05.2020

In the final exam we have **only 6** questions similar to the following:

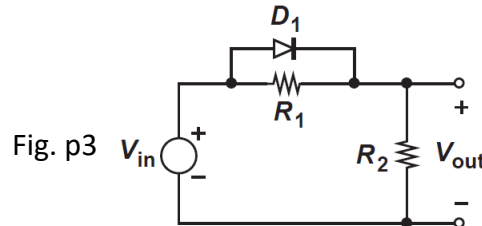
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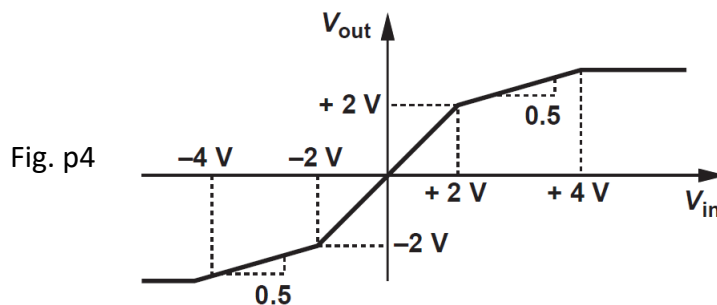
1. A junction employs  $N_D = 5 \times 10^{17} \text{ cm}^{-3}$  and  $N_A = 4 \times 10^{16} \text{ cm}^{-3}$ .
  - (a) Determine the majority and minority carrier concentrations on both sides.
  - (b) Calculate the built-in potential at  $T = 300 \text{ K}$ .
  - (c) Determine the junction capacitance per unit area.
2. For what value of  $I_X$  in Fig. p1, does  $R_1$  carry a current equal to  $I_X/2$ ? Assume  $I_S = 3 \times 10^{-16} \text{ A}$ .



3. Plot the input/output characteristic of the circuits illustrated in Fig. p3 assuming a constant-voltage model.



4. "Wave-shaping" applications require the input/output characteristic illustrated in Fig. p4. Using ideal diodes and other components, construct a circuit that provides such a characteristic. (The value of resistors is not unique).

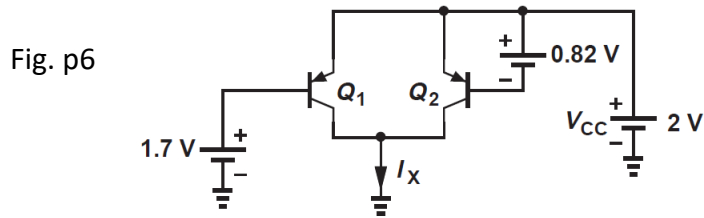


5. A fictitious bipolar transistor exhibits the following relationship between its base and collector currents:

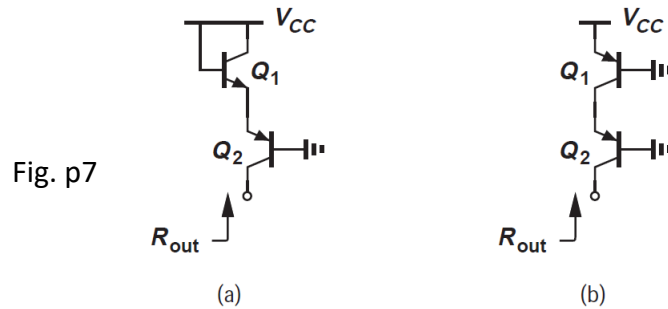
$$I_C = \alpha I_B^2$$

where  $\alpha$  is a constant coefficient. Construct the small-signal model of the device if  $I_C$  is still equal to  $I_S \exp(V_{BE}/V_T)$ .

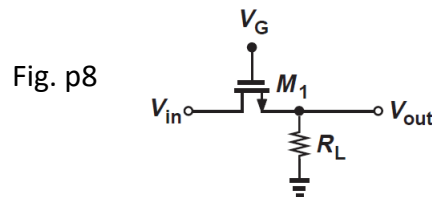
6. If  $I_{S1} = 3I_{S2} = 6 \times 10^{-16}$  A, calculate  $I_X$  in Fig. p6.



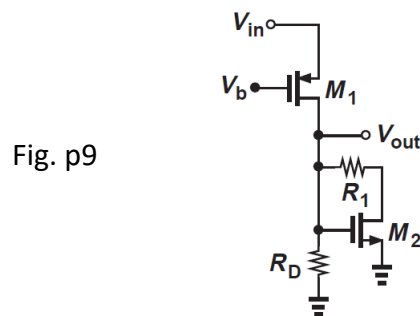
7. Using a small-signal equivalent circuit, compute the output impedances of the stages in Fig. p7 with  $V_A < \infty$ . Assume  $\beta \gg 1$ .



8. In the circuit of Fig. p8,  $M_1$  serves as an electronic switch. If  $V_{in} \approx 0$ , determine  $W/L$  such that the circuit attenuates the signal by only 5%. Assume  $V_G = 1.8$  V and  $R_L = 100 \Omega$ .



9. Construct the small-signal model for the circuit shown in Fig. p9 if all of the transistors operate in saturation and  $\lambda \neq 0$ .



Wish you full success!

$$\epsilon_{Si}=\epsilon_r \text{ (Si)} \times \epsilon_0=11.7\times 8.85\times 10^{-12} \text{ F/m}, k= 1.38\times 10^{-23} \text{ J/K}, \quad D_n = 34 \text{ cm}^2/\text{s}, D_p = 12 \text{ cm}^2/\text{s},$$

$$I_{tot}=I_s(\exp\frac{V_F}{V_T}-1) \qquad I_s=Aqn_i^2(\frac{D_n}{N_AL_n}+\frac{D_p}{N_DL_p})$$

$$V_0=\frac{kT}{q}\ln\frac{N_A N_D}{n_i^2}.$$

$$C_j=\frac{C_{j0}}{\sqrt{1-\frac{V_R}{V_0}}}, \quad C_{j0}=\sqrt{\frac{\epsilon_{si}q}{2}\frac{N_A N_D}{N_A+N_D}\frac{1}{V_0}}, \qquad \frac{D}{\mu}=\frac{kT}{q}.$$

$$J_{tot}=q(\mu_n n+\mu_p p)E \qquad J_{tot}=q(D_ndn/dx-D_pdp/dx)$$

$$V_R \approx \frac{V_p-V_{D,on}}{R_L} \cdot \frac{T_{in}}{C_1} \approx \frac{V_p-V_{D,on}}{R_L C_1 f_{in}},$$

$$I_p \approx C_1 \omega_{in} V_p \sqrt{\frac{2V_R}{V_p}} + \frac{V_p}{R_L} \approx \frac{V_p}{R_L} (R_L C_1 \omega_{in} \sqrt{\frac{2V_R}{V_p}} + 1)$$

$$I_C=\frac{A_EqD_n n_i^2}{N_EW_B}\bigg(\exp\frac{V_{BE}}{V_T}-1\bigg)$$

$$I_C=I_S\exp\frac{V_{BE}}{V_T}$$

$$I_S=\frac{A_EqD_n n_i^2}{N_EW_B} \qquad r_O=\frac{V_A}{I_C}$$

$$V_{TH}=V_{TH0}+\rho\big(\sqrt{2\phi_F+V_{SB}}-\sqrt{2\phi_F}\big)$$

$$I_D=\frac{1}{2}\mu_nC_{ox}\frac{W}{L}\left[2(V_{GS}-V_{TH})V_{DS}-V_{DS}^2\right]$$

$$I_D=\frac{1}{2}\mu_nC_{ox}\frac{W}{L}(V_{GS}-V_{TH})^2(1+\lambda V_{DS}), \qquad r_O=\frac{1}{\lambda I_D}$$

$$R_{on}=\frac{1}{\mu_nC_{ox}\frac{W}{L}(V_{GS}-V_{TH})}.$$

$$g_m=\mu_nC_{ox}\frac{W}{L}(V_{GS}-V_{TH}) \qquad g_m=\frac{2I_D}{V_{GS}-V_{TH}} \qquad g_m=\sqrt{2\mu_nC_{ox}\frac{W}{L}I_D}$$